



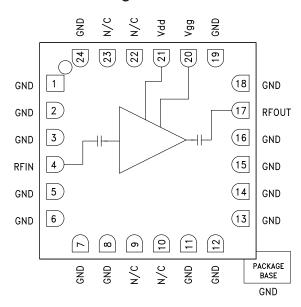
v05.0918

### **Typical Applications**

This HMC504LC4B is ideal for:

- Point-to-Point Radios
- · Point-to-Multi-Point Radios
- Military & Space
- Test Instrumentation

#### **Functional Diagram**



## HMC504LC4B

## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz

#### Features

Noise Figure: 2.2 dB @ 20 GHz Gain: 19 dB P1dB Output Power: +17 dBm Supply Voltage: +4V @ 90mA Output IP3: +26 dBm 50 Ohm matched Input/Output 24 Lead 4x4mm SMT Package: 16mm<sup>2</sup>

#### **General Description**

The HMC504LC4B is a GaAs MMIC Low Noise Wideband Amplifier housed in a leadless 4x4 mm ceramic surface mount package. The amplifier operates between 14 and 27 GHz, providing up to 19 dB of small signal gain, 2.2 dB noise figure, and output IP3 of +26 dBm, while requiring only 90 mA from a +4V supply. The P1dB output power of up to +17 dBm enables the LNA to function as a LO driver for balanced, I/Q or image reject mixers. The HMC504LC4B also features I/Os that are DC blocked and internally matched to 50 Ohms, making it ideal for high capacity microwave radios or VSAT applications. This versatile LNA is also available in die form as the HMC-ALH476.

#### Electrical Specifications, $T_A = +25 \text{ °C}$ , Vdd = +4V, Idd = 90 mA<sup>[2]</sup>

| Parameter  | Min. | Тур.    | Max. | Min. | Тур.    | Max. | Min. | Тур.    | Max. | Units |
|--|------|---------|------|------|---------|------|------|---------|------|-------|
| Frequency Range                                      |      | 14 - 20 |      |      | 20 - 24 |      |      | 24 - 27 |      | GHz   |
| Gain <sup>[1]</sup>                                  | 16.5 | 19      |      | 16   | 18.5    |      | 14   | 17      |      | dB    |
| Gain Variation over Temperature                      |      | 0.015   |      |      | 0.017   |      |      | 0.018   |      | dB/°C |
| Noise Figure <sup>[1]</sup>                          |      | 2.2     | 3    |      | 2.5     | 4.2  |      | 4.5     | 6    | dB    |
| Input Return Loss                                    |      | 15      |      |      | 9       |      |      | 7       |      | dB    |
| Output Return Loss                                   |      | 15      |      |      | 12      |      |      | 9.5     |      | dB    |
| Output Power for 1 dB Compression [1]                |      | 15      |      |      | 16.5    |      |      | 17      |      | dBm   |
| Saturated Output Power (Psat) [1]                    |      | 19.5    |      |      | 19.5    |      |      | 19      |      | dBm   |
| Output Third Order Intercept (IP3)                   |      | 24.5    |      |      | 25.5    |      |      | 26      |      | dBm   |
| Supply Current (Idd)<br>(Vdd = 4V, Vgg = -0.3V Typ.) |      | 90      |      |      | 90      |      |      | 90      |      | mA    |

[1] Board loss subtracted out for gain, power and noise figure measurement [2] Adjust Vgg between -1.7 to 0V to achieve Idd = 90mA

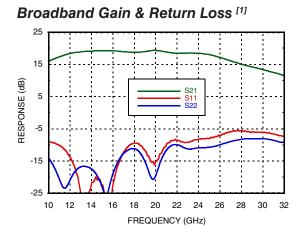
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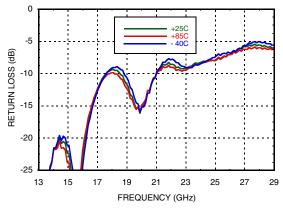
# HMC504LC4B



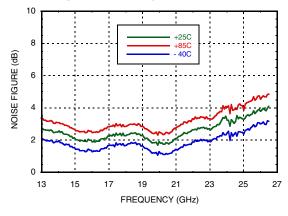
## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz



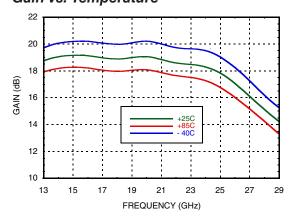
Input Return Loss vs. Temperature



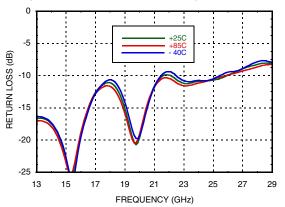
Noise Figure vs. Temperature [1]



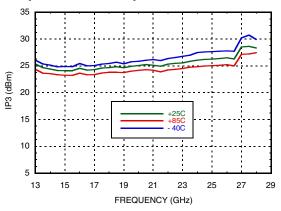
Gain vs. Temperature [1]



Output Return Loss vs. Temperature



Output IP3 vs. Temperature

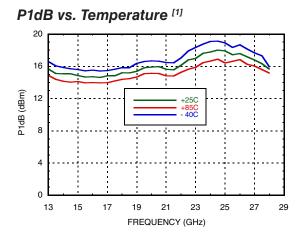


 $\left[1\right]$  Board loss subtracted out for gain, power and noise figure measurement

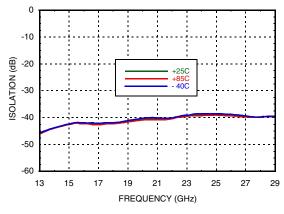




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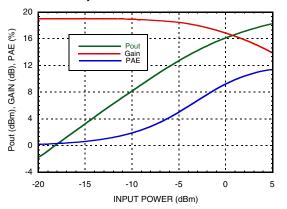


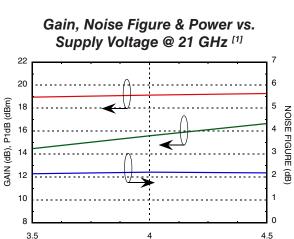
Reverse Isolation vs. Temperature



Psat vs. Temperature [1] 24 20 Psat (dBm) 16 +25C 12 -850 40C 8 Λ 29 13 15 17 19 21 23 25 27 FREQUENCY (GHz)

Power Compression @ 21 GHz [1]





[1] Board loss subtracted out for gain, power and noise figure measurement

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

Vdd (V)



### HMC504LC4B v05.0918

02-27-2017-A

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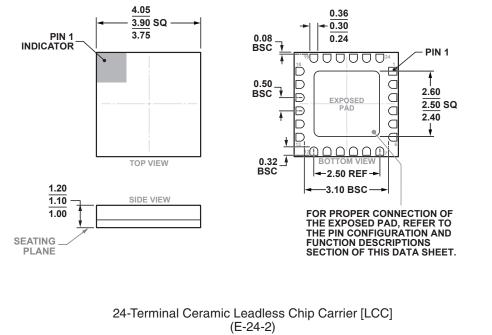
### Absolute Maximum Ratings

| Drain Bias Voltage  | +4.5V          |
|---|----------------|
| RF Input Power  | +6 dBm         |
| Gate Bias Voltage   | -2 to 0.3V     |
| Channel Temperature   | 180 °C         |
| Continuous Pdiss (T = 85 °C)<br>(derate 20 mW/°C above 85 °C) | 1.9 W          |
| Thermal Resistance<br>(Channel to ground paddle)              | 50 °C/W        |
| Storage Temperature   | -65 to +150 °C |
| Operating Temperature   | -40 to +85 °C  |
| ESD Sensitivity (HBM)   | Class 1A       |



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## **Outline Drawing**



Dimensions shown in millimeters

#### Package Information

| Part Number                               | Package Body Material | Lead Finish      | MSL Rating          | Package Marking <sup>[2]</sup> |  |
|---|-----------------------|------------------|---------------------|--------------------------------|--|
| HMC504LC4B                                | Alumina, White        | Gold over Nickel | MSL3 <sup>[1]</sup> | H504<br>XXXX                   |  |
| [1] Max peak reflow temperature of 260 °C |                       |                  |                     |                                |  |

[2] 4-Digit lot number XXXX



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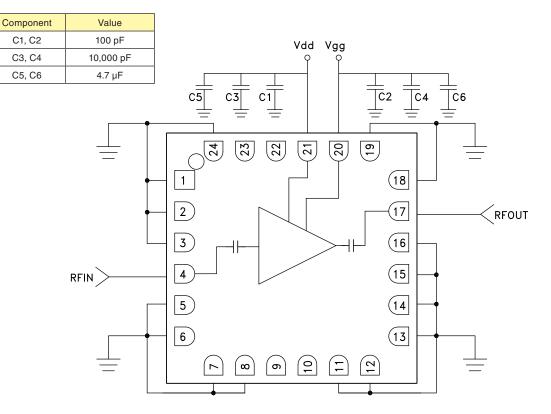


## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz

### **Pin Descriptions**

| Pin Number                           | Function | Description   | Interface Schematic |  |
|--------------------------------------|----------|---|---------------------|--|
| 1 - 3, 5 - 8, 11 - 16,<br>18, 19, 24 | GND      | Package bottom has exposed metal paddle that must be connected to RF/DC ground.   |                     |  |
| 4                                    | RFIN     | This pad is AC coupled and matched to 50 Ohms.  |                     |  |
| 17                                   | RFOUT    | This pad is AC coupled and matched to 50 Ohms.  |                     |  |
| 20                                   | Vgg      | Gate control for amplifier. Please follow "MMIC Amplifier Bias-<br>ing Procedure" application note. See assembly for required<br>external components. | Vgg o               |  |
| 21                                   | Vdd      | Power Supply Voltage for the amplifier. See assembly for required external components.  | Vdd o               |  |

## **Application Circuit**



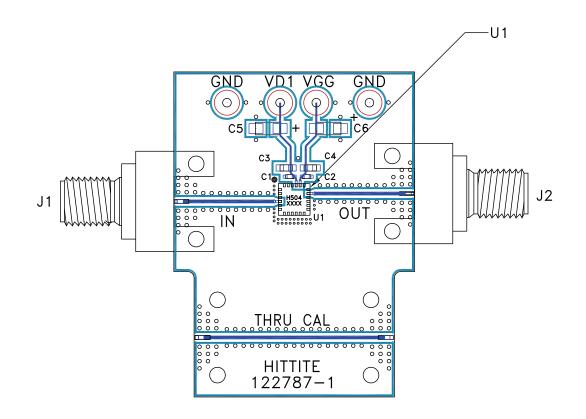


## HMC504LC4B

## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz



#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 122789 [1]

| Item    | Description                          |
|---------|--------------------------------------|
| J1, J2  | 2.92mm PCB mount K-Connector         |
| J3 - J6 | DC Pin                               |
| C1, C2  | 100 pF Capacitor, 0402 Pkg.          |
| C3, C4  | 10,000pF Capacitor, 0603 Pkg.        |
| C5, C6  | 4.7 µF Capacitor, Tantalum           |
| U1      | HMC504LC4B Amplifier                 |
| PCB [2] | 122787 Evaluation PCB <sup>[3]</sup> |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

[3] Due to the very high frequency operation of this product a custom LC4B PCB footprint and solder stencil are required for this design. Performance shown in this data sheet was produced using this custom footprint. DO NOT USE Hittite's standard LC4B footprint. Please contact Applications for details. The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices, upon request.

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